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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/019,407	03/25/2002	Yoshinobu Kimura	520.41003 X00	3893
	7590 09/10/200 TERRY, STOUT & K	EXAMINER		
1300 NORTH SEVENTEENTH STREET SUITE 1800			SCHILLINGER, LAURA M	
	VA 22209-3873		ART UNIT	PAPER NUMBER
			2813	
	•		MAIL DATE	DELIVERY MODE
			09/10/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

		$\mathcal{G}M$
	Application No.	Applicant(s)
Office Antice Comment	10/019,407	KIMURA ET AL.
Office Action Summary	Examiner	Art Unit
	Laura M. Schillinger	2813
The MAILING DATE of this communication appeared for Reply	pears on the cover sheet wi	th the correspondence address
A SHORTENED STATUTORY PERIOD FOR REPL WHICHEVER IS LONGER, FROM THE MAILING D - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNION (136(a). In no event, however, may a rewill apply and will expire SIX (6) MON a. cause the application to become AB	CATION. eply be timely filed ITHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).
Status		
Responsive to communication(s) filed on 17 № This action is FINAL . 2b) This Since this application is in condition for alloware closed in accordance with the practice under N	s action is non-final. nce except for formal matt	• •
Disposition of Claims		•
4) ⊠ Claim(s) 1-13 and 16-20 is/are pending in the 4a) Of the above claim(s) 1,2,5-13 and 16-20 i 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) 3 is/are rejected. 7) ⊠ Claim(s) 4 is/are objected to. 8) □ Claim(s) are subject to restriction and/o	s/are withdrawn from cons	ideration.
Application Papers		
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) accomplicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Examine 11.	cepted or b) objected to drawing(s) be held in abeyantion is required if the drawing	nce. See 37 CFR 1.85(a). (s) is objected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Burea * See the attached detailed Office action for a list	ts have been received. ts have been received in A prity documents have been u (PCT Rule 17.2(a)).	pplication No received in this National Stage
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	Paper No(s	Summary (PTO-413) s)/Mail Date nformal Patent Application

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DETAILED ACTION

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claim 3 is rejected under 35 U.S.C. 102(e) as being anticipated by Noguchi et al ('380).

3. (Previously Presented) A semiconductor device comprising plural transistors formed in a polycrystalline semiconductor thin film, wherein the polycrystalline semiconductor thin film is formed by a plurality of laser irradiation steps, wherein the laser irradiation steps are carried out so that, after the last laser irradiation step, the number of crystal grains with the number of closest crystal grains of 6 is greatest among plural crystal grains that form the polycrystalline semiconductor thin film (Fig.10-12).

Allowable Subject Matter

Claim 4 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

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Noguchi fails to teach nor suggest the language recited in claim 4, that is wherein the roughness of the grain boundaries is 5nm or less. Consequently, claim 4 contains allowable subject matter.

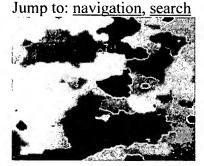
Response to Arguments

Applicant's arguments filed 5/17/07 have been fully considered but they are not persuasive.

Applicant argues that Noguchi teaches a single crystal structure in contrast to Applicant's claim which requires a polycrystalline film. However, it is noted that the definition of polycrystal (polycrystalline) is as follows as provided by Wikipedia.com:

"Polycrystal

From Wikipedia, the free encyclopedia



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A photo of <u>electrical steel</u> (coating removed) showing polycrystalline structure A **polycrystal** is a material that is made of many smaller and randomly oriented <u>crystallites</u>. *Cf.* monocrystal.

Almost all common <u>metals</u>, and many <u>ceramics</u> are polycrystalline. The crystallites are often referred to as grains.

Polycrystalline is a structure of a solid, such as brass, that when cooled form liquid crystals formed from different points within it. This creates many crystals within a structure, where these crystals meet is known as a grain boundary. "

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Therefore, it is understood that polycrystalline is a crystalline material made of multiple grains. As Noguchi teaches in Fig.s 10-12, the material has multiple single grain crystals and is therefore a polycrystalline film. The difference between Noguchi's polycrystalline and a conventional polycrystalline material is that the crystals are oriented in the same direction.

Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Laura M. Schillinger whose telephone number is (571) 272-1697. The examiner can normally be reached on M-T, R-F 7:00-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl W. Whitehead, Jr. can be reached on (571) 272-1702. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

09/02/07

Laura M Schillinger Primary Examiner Art Unit 2813